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VOLTAGE RATINGS

Part Number	V _{RRM} , V _R (V) rep. peak reverse voltage		Max. T _J = 0 to 180°C	V _{RSM} , V _R (V) Max. non-rep. peak reverse voltage T _J = -40 to 0°C
	T _J = -40 to 0°C	T _J = 25 to 180°C		
A5A:2800.02	200	200		300
A5A:2800.04	400	400		500
A5A:2800.06	600	600		700
A5A:2800.08	800	800		900
A5A:2800.10	1000	1000		1100
A5A:2800.12	1200	1200		1300

MAXIMUM ALLOWABLE RATINGS

PARAMETER	VALUE	UNITS	NOTES
T _J Junction Temperature	-40 to 180	°C	-
T _{stg} Storage Temperature	-40 to 180	°C	-
I _{F(AV)} Max. Av. current @ Max. T _C	2300 125	A °C	180° half sine wave
I _{F(RMS)} Nom. RMS current	4420	A	-
I _{FSM} Max. Peak non-rep. surge current	28.7	kA	50 Hz half cycle sine wave Initial T _J = 180°C, rated V _{RRM} applied after surge.
	30.0		60 Hz half cycle sine wave
	34.1		50 Hz half cycle sine wave Initial T _J = 180°C, no voltage applied after surge.
	35.7		60 Hz half cycle sine wave
I ² t Max. I ² t capability	4110	kA ² s	t = 10ms Initial T _J = 180°C, rated V _{RRM} applied after surge.
	3750		t = 8.3 ms
	5810		t = 10ms Initial T _J = 180°C, no voltage applied after surge.
	5300		t = 8.3 ms
I ² t ^{1/2} Max. I ² t ^{1/2} capability	58100	kA ² s ^{1/2}	Initial T _J = 180°C, no voltage applied after surge. I ² t for time t _x = I ² t ^{1/2} * t _x ^{1/2} . (0.1 < t _x < 10ms).
F Mounting Force	2500	N.m	-



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CHARACTERISTICS

PARAMETER	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
V_{FM} Peak forward voltage	---	1.35	1.53	V	Initial $T_J = 25^\circ\text{C}$, 50-60Hz half sine, $I_{peak} = 7225\text{A}$.
$V_{F(TO)1}$ Low-level threshold	---	---	0.786	V	$T_J = 180^\circ\text{C}$
$V_{F(TO)2}$ High-level threshold	---	---	0.805		$\text{Av. power} = V_{F(TO)} * I_{F(AV)} + r_F * [I_{F(RMS)}]^2$
r_{F1} Low-level resistance	---	---	0.1	m	Use low values for $I_{FM} < I_{F(AV)}$
r_{F2} High-level resistance	---	---	0.086		
I_{RM} Peak reverse current	---	30	100	mA	$T_J = 180^\circ\text{C}$. Max. rated V_{RRM}
R_{thJC} Thermal resistance, junction-to-case	---	---	0.023	$^\circ\text{C/W}$	DC operation, double side
	---	---	0.025	$^\circ\text{C/W}$	180° sine wave, double side
	---	---	0.025	$^\circ\text{C/W}$	120° rectangular wave, double side
R_{thCS} Thermal resistance, case-to-sink	---	---	0.02	$^\circ\text{C/W}$	Mtg. Surface smooth, flat and greased. Double side cooled.
wt Weight	---	425(15)	---	g(oz.)	---
Case Style	A-24				---

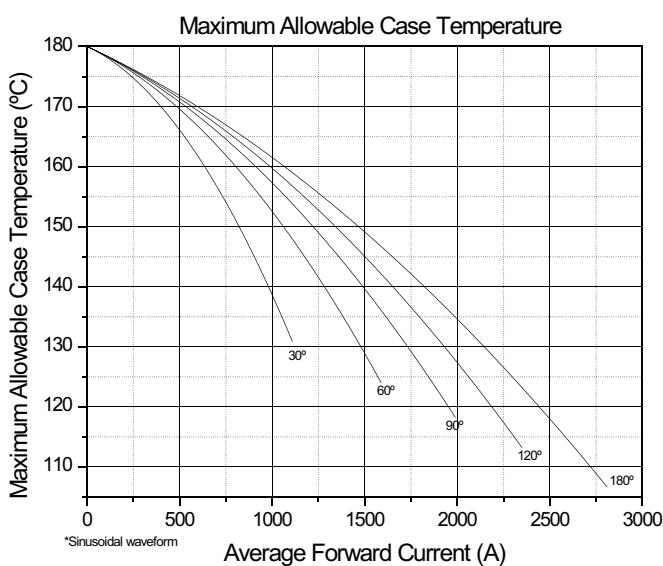


Fig. 1 - Current Ratings Characteristics

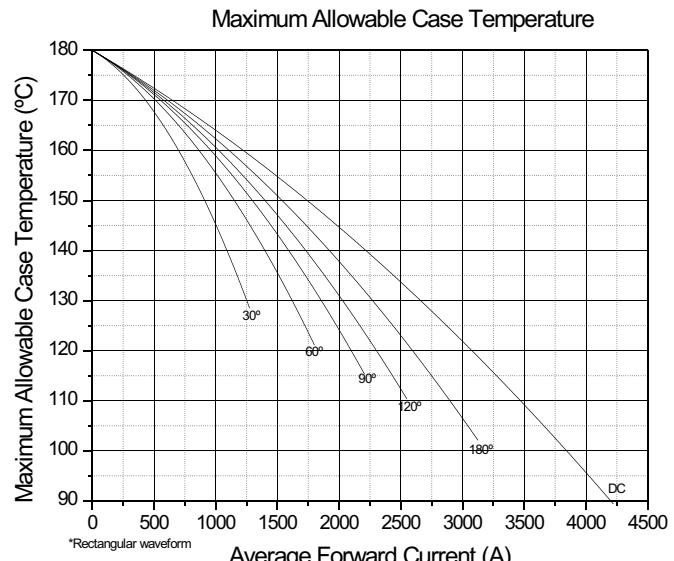


Fig. 2 - Current Ratings Characteristics



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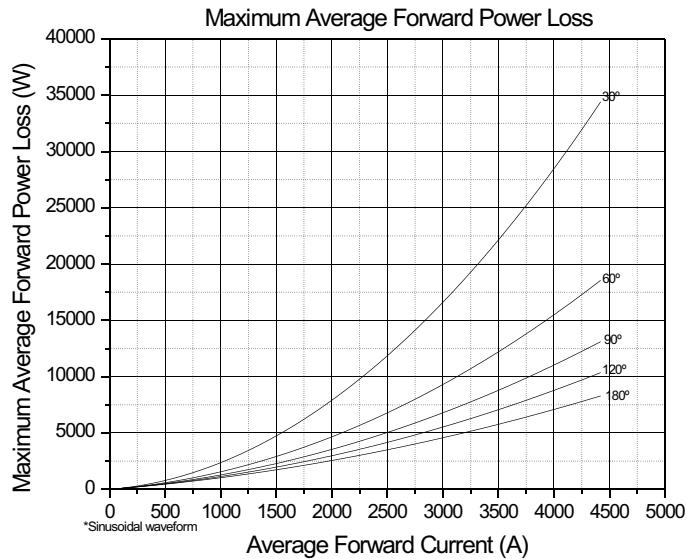


Fig. 3 - Average Forward Power Loss Characteristics

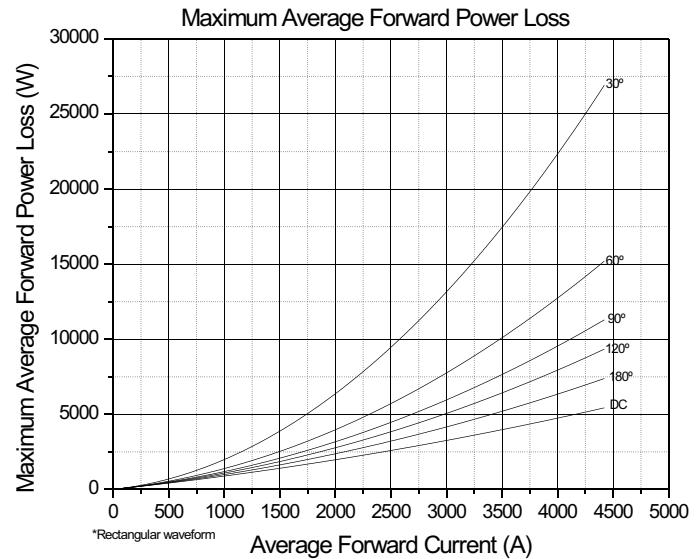


Fig. 4 - Average Forward Power Loss Characteristics

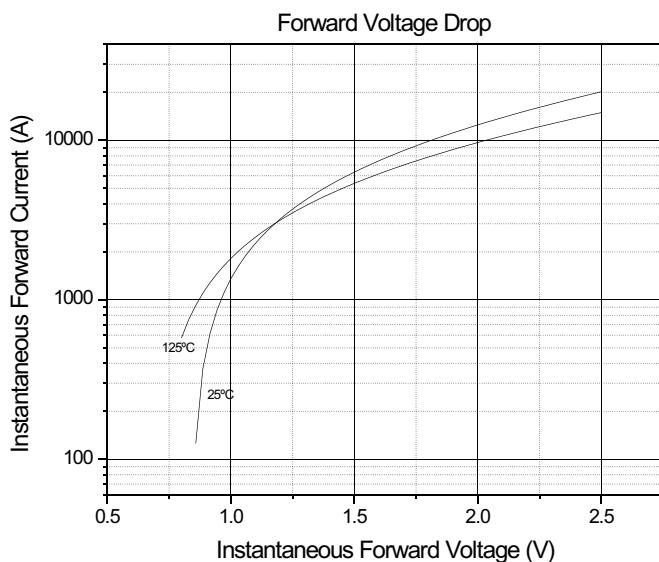


Fig. 5 - Forward Voltage Drop Characteristics

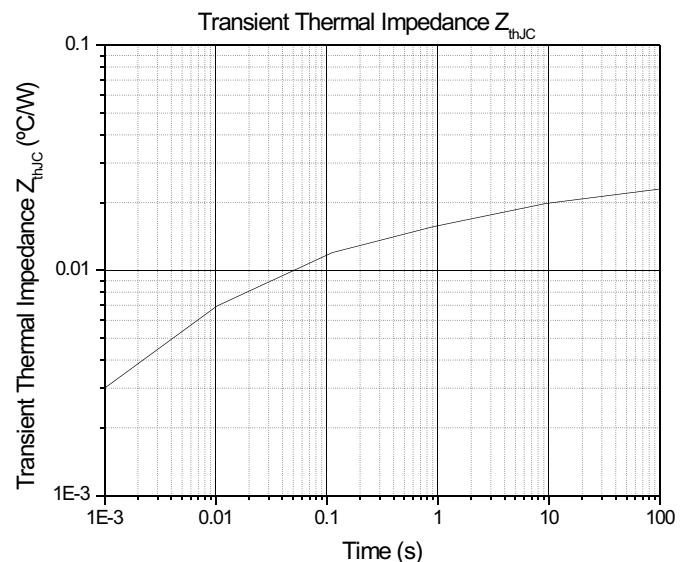


Fig. 6 - Transient Thermal Impedance Z_{thJC} Characteristics



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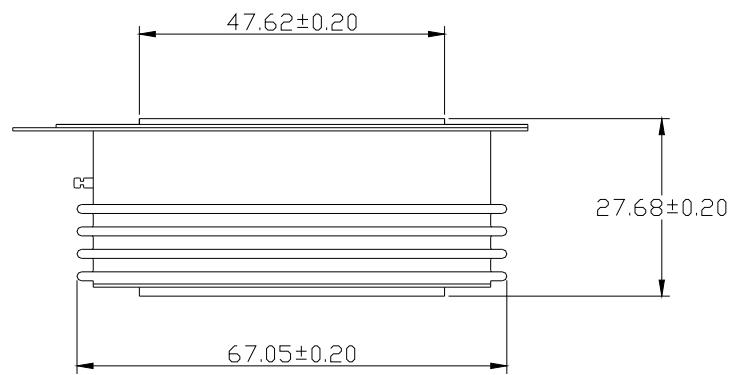
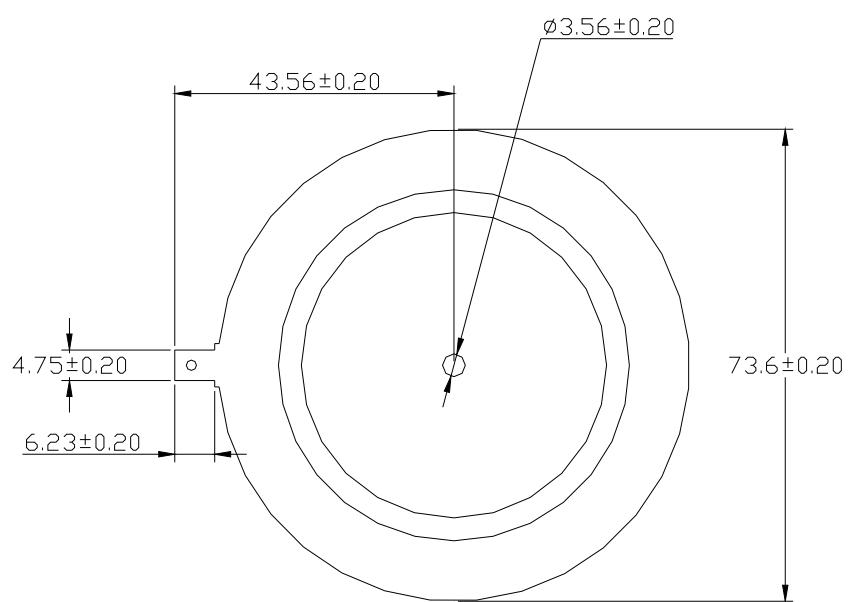


Fig. 7 - Outline Characteristics